REVERSE VOLTAGE - 60 Volts
FORWARD CURRENT -5.0 Amperes FORWARD CURRENT - 5.0 Amperes

## FEATURES

- Metal-Semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection application


## MECHANICAL DATA

- Case : JEDEC DO-201AD molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.04 ounces, 1.1 grams
- Mounting position : Any
- Component in accordance to RoHs 2002/95/EC

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
Ratings at $25^{\circ} \mathrm{C}$ ambient temperature unless otherwise specified.

| CHARACTERISTICS |  | SYMBOL | SB560L | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| Maximum Repetitive Peak Reverse Voltage |  | $V_{\text {RRM }}$ | 60 | V |
| Maximum RMS Voltage |  | $\mathrm{V}_{\text {RMS }}$ | 42 | V |
| Maximum DC Blocking Voltage |  | $\mathrm{V}_{\mathrm{DC}}$ | 60 | V |
| Maximum Average Forward Rectified Current |  | $\mathrm{I}_{\mathrm{AV}}$ | 5.0 | A |
| Peak Forward Surge 8.3 ms single half sine-wave superimposed on rated load |  | $I_{\text {FSM }}$ | 150 | A |
| Maximum Forward Voltage at 5.0A DC |  | $V_{F}$ | 0.55 | V |
| Maximum DC Reverse Current at Rated DC Blocking Voltage | @ $T j=25^{\circ} \mathrm{C}$ <br> @Tj=100․ C | $\mathrm{I}_{\mathrm{R}}$ | $\begin{aligned} & 0.1 \\ & 20 \end{aligned}$ | mA |
| Thermal Resistance. Junction to Lead (Note 1) |  | R JL | 8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction to Case (Note 1) |  | RөJC | 10 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction to Ambient (Note 1) |  | R JAA | 30 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Typical Junction Capacitance (Note 2) |  | Cj | 430 | pF |
| Operating Junction Temperature Range |  | Tj | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range |  | TSTG | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| : Note (1) Unit mounted on glass-epoxy substrate with 10z/ft2_ø5mm |  |  |  | REV.1, Oct-2010, KDHF15 |

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC .

FIG.1-FORWARD CURRENT DERATING CURVE


FIG.3-TYPICAL JUNCTION CAPACITANCE


FIG.5- TYPICAL REVERSE CHARACTERISTICS


FIG.2-MAXIMUM NON-REPETITIVE SURGE


FIG.4-TYPICAL FORWARD CHARACTERISTICS


FIG.6- DC REVERSE VOLTAGE DERATING CURVE


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